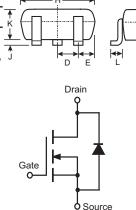




N-CHANNEL ENHANCEMENT MODE FIELD EFFECT TRANSISTOR

Features

- Low On-Resistance
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Ultra-Small Surface Mount Package
- Lead Free/RoHS Compliant (Note 2)
- "Green" Device (Note 3 and 4)
- Mechanical Data
- Case: SOT-323
- Case Material: Molded Plastic, "Green" Molding Compound, Note 4. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminals: Finish Matte Tin annealed over Alloy 42 leadframe. Solderable per MIL-STD-202, Method 208
- Terminal Connections: See Diagram
- Marking (See Page 2): K72
- Ordering & Date Code Information: See Page 2
- Weight: 0.006 grams (approximate)



вС

| SOT-323 | | | | | | | | | |
|----------------------|--------|--------|--|--|--|--|--|--|--|
| Dim | Min | Мах | | | | | | | |
| Α | 0.25 | 0.40 | | | | | | | |
| В | 1.15 | 1.35 | | | | | | | |
| С | 2.00 | 2.20 | | | | | | | |
| D | 0.65 N | ominal | | | | | | | |
| E | 0.30 | 0.40 | | | | | | | |
| G | 1.20 | 1.40 | | | | | | | |
| Н | 1.80 | 2.20 | | | | | | | |
| J | 0.0 | 0.10 | | | | | | | |
| К | 0.90 | 1.00 | | | | | | | |
| L | 0.25 | 0.40 | | | | | | | |
| М | 0.10 | 0.18 | | | | | | | |
| α | 0° | 8° | | | | | | | |
| All Dimensions in mm | | | | | | | | | |

Maximum Ratings @ T_A = 25°C unless otherwise specified

| Charact | eristic | Symbol | 2N7002W | Units | | |
|--|---------------|----------------------|------------------|-------------|--|--|
| Drain-Source Voltage | | V _{DSS} | 60 | V | | |
| Drain-Gate Voltage $R_{GS} \le 1.0I$ | MΩ | V _{DGR} | 60 | V | | |
| Gate-Source Voltage Continuous Pulsed | | V _{GSS} | ±20 ±40 | V | | |
| Drain Current (Note 1) Continuous Continuous @ 100°C Pulsed | | ID | 115 73 800 | mA | | |
| Total Power Dissipation (Note Derating above $T_A = 25^{\circ}C$ | 1) | Pd | 200 1.60 | mW mW/°C | | |
| Thermal Resistance, Junction | to Ambient | R _{θJA} | 625 | K/W | | |
| Operating and Storage Tempe | erature Range | Tj, T _{STG} | -55 to +150 | °C | | |

Note: 1. Device mounted on FR-5 PCB 1.0 x 0.75 x 0.062 inch pad layout as shown on Diodes, Inc. suggested pad layout AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.

2. No purposefully added lead.

3. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.

4. Product manufactured with Date Code 0609 (week 9, 2006) and newer are built with Green Molding Compound. Product

manufactured prior to Date Code 0609 are built with Non-Green Molding Compound and may contain Halogens or Sb2O3 Fire Retardants.



| lectrical Chacteristics | @ T _A = 25°C un | less otherv | vise spec | cified | | | | |
|--|---|----------------------|-----------|------------|-------------|----------------|---|--|
| Characteristic | Symbol Min | | Тур | Max | Unit | Test Condition | | |
| OFF CHARACTERISTICS (Note 5) | | | | | 1 | • | I | |
| Drain-Source Breakdown Voltage | | BV _{DSS} | 60 | 70 | _ | V | $V_{GS} = 0V, I_D = 10\mu A$ | |
| Zero Gate Voltage Drain Current @ $T_C = 25^{\circ}C$ @ $T_C = 125^{\circ}C$ | | I _{DSS} | _ | _ | 1.0 500 | μA | $V_{DS} = 60V, V_{GS} = 0V$ | |
| Gate-Body Leakage | | IGSS | | _ | ±10 | nA | $V_{GS} = \pm 20V, V_{DS} = 0V$ | |
| ON CHARACTERISTICS (Note 5) | | | | | | | • | |
| Gate Threshold Voltage | | V _{GS(th)} | 1.0 | | 2.0 | V | $V_{DS} = V_{GS}, I_D = 250 \mu A$ | |
| Static Drain-Source On-Resistance | @ T _j = 25°C @ T _j = 125°C | R _{DS (ON)} | | 1.8 2.6 | 7.5 13.5 | 0 | $V_{GS} = 5.0V, I_D = 0.05A$ | |
| | @ T _j = 125°C | | | | | 52 | $V_{GS} = 10V, I_D = 0.5A$ | |
| On-State Drain Current | | I _{D(ON)} | 0.5 | 1.0 | | A | $V_{GS} = 10V, V_{DS} = 7.5V$ | |
| Forward Transconductance | | g fs | 80 | | _ | mS | $V_{DS} = 10V, I_D = 0.2A$ | |
| DYNAMIC CHARACTERISTICS | | | | | | | • | |
| Input Capacitance | | Ciss | | 22 | 50 | pF | | |
| Output Capacitance | | | | 11 | 25 | pF | $V_{DS} = 25V, V_{GS} = 0V$ f = 1.0MHz | |
| Reverse Transfer Capacitance | | | | 2.0 | 5.0 | pF | | |
| SWITCHING CHARACTERISTICS | | | | | 1 | | | |
| Turn-On Delay Time | | t _{D(ON)} | | 7.0 | 20 | ns | $V_{DD} = 30V, I_D = 0.2A,$ | |
| Turn-Off Delay Time | | | _ | 11 | 20 | ns | $R_L = 150\Omega$, $V_{GEN} = 10V$, $R_{GEN} = 25\Omega$ | |

Ordering Information (Note 4 and 6)

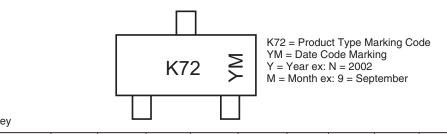
| Device | Packaging | Shipping | | |
|-------------|-----------|------------------|--|--|
| 2N7002W-7-F | SOT-323 | 3000/Tape & Reel | | |

Notes: 4. Product manufactured with Date Code 0609 (week 9, 2006) and newer are built with Green Molding Compound. Product manufactured prior to Date Code 0609 are built with Non-Green Molding Compound and may contain Halogens or Sb2O3 Fire Retardants.

5. Short duration test pulse used to minimize self-heating effect.

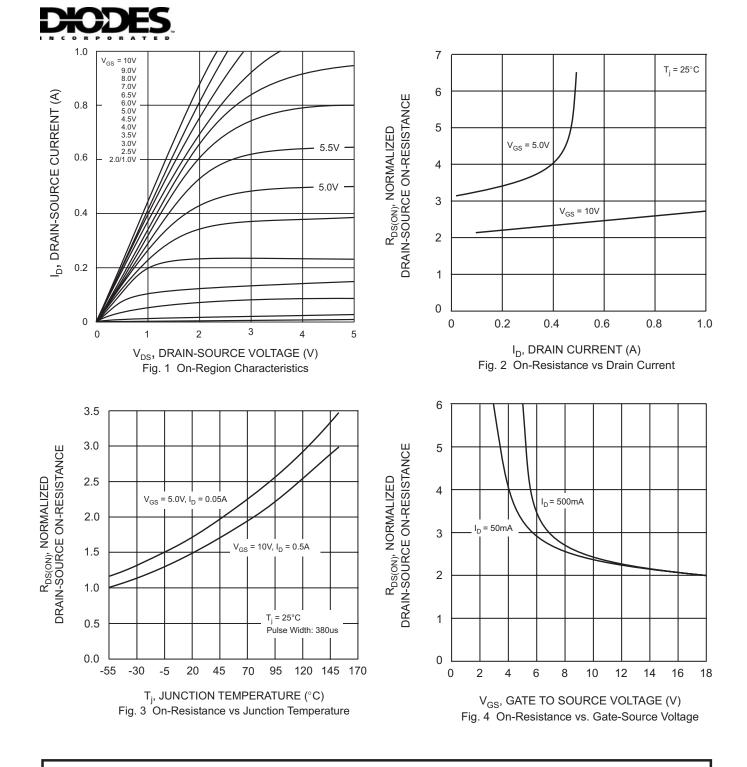
6. For Packaging Details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

Marking Information



Date Code Key

| Year | 1998 | 1999 | 2000 | 2001 | 2002 | 2003 | 2004 | 2005 | 2006 | 2007 | 2008 | 2009 |
|---|------|------|------|------|------|------|------|------|------|------|------|------|
| Code | J | К | L | М | Ν | Р | R | S | Т | U | V | W |
| Month Jan Feb March Apr May Jun Jul Aug Sep Oct Nov Dec | | | | | | | | | | | | |
| Code | 1 | 2 | 3 | 4 | 5 | 6 | 7 | 8 | 9 | 0 | N | D |



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